NSN 5961-01-411-1962

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic or glass or plastic
Overall Length:
0.205 inches
End Application:
Detector proc
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
21.0 reverse voltage, instantaneous and 30.0 repetitive peak reverse voltage, peak total value
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0